



SC5407A/SC5408A 100 kHz to 6 GHz RF Upconverter

Datasheet

Rev 1.2

© 2017 SignalCore, Inc. support@signalcore.com

PRODUCT SPECIFICATIONS

Definition of Terms

The following terms are used throughout this datasheet to define specific conditions:

Specification (spec)	 Defines guaranteed performance of a calibrated instrument under the following conditions: 3 hours storage at room temperature (standardized to 25 °C) followed by 30 minutes minimum warm-up operation. Specified environmental conditions are met within the specified operating temperature range of 0 °C to 40 °C unless otherwise noted. Recommended calibration intervals are used.
Typical data (typ)	When used with <, > or in a range, defines performance met by approximately 80% of all instruments manufactured. This data is not guaranteed, does not include measurement uncertainty, and is valid only at room temperature (standardized to 25 °C).
Nominal values (nom)	Characterizes product performance by means of average performance of a representative value for the given parameter (e.g. nominal impedance). This data is not guaranteed and is valid only at room temperature (standardized to 25 °C).
Measured values (meas)	Characterizes expected product performance by means of measurement results gained from individual samples.

Specifications are subject to change without notice. For the most recent product specifications, visit www.signalcore.com.

Spectral Specifications

RF output range	
Direct path 100 kHz	to 400 MHz
Conversion path	z to 6.0 GHz
IF2 output frequency	1.25 GHz
IF input center frequency ⁽¹⁾	
First (IF3) stage conversion enabled	to 500 MHz
Second IF selected (Bypass IF3 conversion)	1.25 GHz
RF output polarity ⁽²⁾	
First (IF3) stage conversion enabled	ed/Inverted
Second IF selected (Bypass IF3 conversion)	Inverted
IF bandwidth (3 dB)	
First (IF3) stage conversion enabled 8	30/160 MHz
(Contact SignalCore other IF BW options) ⁽¹⁾	
IF3 conversion bypassed (2 stage conversion)	320 MHz



Figure 1. Typical relative output RF responses of bandpass filters measured at 1.5 GHz with center IF of 240 MHz. The noise floor of the power meter limits the out-of-band rejection measurement.

- (1) The IF may be selected to drive either the output RF, second, or third conversion stages. If the output RF port is selected, the signal to the RF port is directly routed from the IF port, bypassing the conversion process entirely. The frequency range of this path is 100 kHz to 400 MHz. When the second stage is selected, the IF is fixed at 1.25 GHz, and the RF spectrum is inverted with respect to the IF. When the third stage is selected, the IF center frequency is tunable from 1 MHz to 500 MHz in 5 MHz steps. Although the tuning range provides flexibility, the IF bandwidth may practically limit the center frequency. The lowest usable IF frequency for an IF bandwidth of 80 MHz is 90 MHz, and for large bandwidths the IF will need to increase. Lower IF frequencies can be used if a lower bandwidth filter is optionally requested; a 40 BW filter will allow IF as low as 70 MHz.
- (2) The RF output polarity refers to the conversion polarity of the downconverter. When the polarity is inverted, the spectral content of the output is inverted with respect to the input; this process is commonly known as "spectral inversion" or "spectral flipping". The choice depends on the application. For digitizers that are sampling the IF in the even-order Nyquist zones that naturally inverts spectra, having the IF polarity inverted will produce non-inverted baseband, and vice-versa. However, this is only a convenience in this application case because inverted spectrum, once digitized, can easily be re-inverted mathematically. This selectable inversion option is only available when the IF3 conversion stage is selected. When the IF3 conversion is bypassed (2 stage conversion), the output spectrum is always inverted.

RF tuning

Frequency step resolution ⁽³⁾	1 H	Z
Lock and settling times ⁽⁴⁾	1 m	S



Figure 2. Typical frequency settling time versus tuning step frequency.

- (3) Tuning resolution of 1 mHz is available.
- (4) Locked and settled to < 1 ppm of final frequencies of > 500 MHz and step size of < 10 MHz. For final frequencies < 500 MHz the settle time applies to accuracy with 500 Hz of the final frequency for a 10 MHz step. See Figure 2 for examples of other tuning step settling times. When fast-tune mode is enabled the noise damping capacitor across the main YIG tuning coil is disengaged, resulting in an increase of the rate of current flow through the coil and settling to a steady state quicker. Lock time begins when the full tuning word command is received by the device.</p>

Frequency reference (5)

Technology	Temperature compensated crystal oscillator
Accuracy ± [(aging x last adjust	ment time lapse) + temp stability + cal accuracy]
Initial calibration accuracy	±0.05 ppm
Temperature stability ⁽⁶⁾	
20 °C to 30 °C	±0.25 ppm
0 °C to 55 °C	±1.0 ppm
Aging	±1 ppm for first year @ 25 °C

Frequency accuracy⁽⁷⁾ ± (frequency reference accuracy * RF output frequency) Hz

- (5) The frequency reference refers to the device's internal 10 MHz TCXO time-base. Accuracy is in parts-per-million or ppm $(1x10^{-6})$.
- (6) Users must apply sufficient cooling to the device to keep the unit temperature as read from its internal temperature sensor within the range of 40 °C to 45 °C at an ambient temperature of 25 °C.
- (7) Accuracy of the device for any given input RF signal.

Sideband noise (dBc/Hz) ⁽⁸⁾⁽⁹⁾

RF Frequency				
Offset	100 MHz	2000 MHz	4000 MHz	5500 MHz
100 Hz	-80	-78	-76	-74
1 kHz	-95	-93	-91	-89
10 kHz	-100	-97	-95	-93
100 kHz	-112	-110	-110	-109
1 MHz	-139	-138	-138	-137
10 MHz	-148	-147	-144	-143



Figure 3. Typical measured sideband noise.⁽⁹⁾

- (8) Sideband phase noise as specified is based on measured sideband noise which includes both phase noise and amplitude noise contributions. Sideband noise is specified for the upconverter when tune mode is set to NORMAL. In FAST-TUNE mode the noise damping capacitor across the YIG tuning coil is disengaged, and thus the close-in phase noise degrades. See the appropriate sections in the user manual for further information on how to set the device to NORMAL or FAST-TUNE modes.
- (9) These results are obtained with input signal levels of 5 dBm at the IF3 mixer (no IF3 attenuation) and the output RF level set to >3 dBm. The upconverter is set for best SNR, a setting suitable for generating single tone CW signals.

LO related sideband spurious signals (10)(11)

< 200 kHz	70 dBc
> 200 kHz	75 dBc

- (10) Sideband spurious signals are those that fall within 2 MHz of the carrier that are direct results of the local oscillators in the device. Sources of sideband spurious signals in the synthesized local oscillators are primarily due to fractional-N spurious products in the PLL's, DDS noise sources, and intermodulation between oscillators within the multiple-loop PLL synthesizers. Fractional-N and DDS spurious products affect spectral regions below 200 kHz and intermodulation products affect spectral regions out to a couple MHz.
- (11) As the YIG oscillator is sensitive to magnetic fields, magnetic noise due to electrical fans, supply transformers, and other magnetic field-producing devices may induce sideband noise on the signals when they are placed in close proximity. It is recommended that users exercise good technical judgment when such accessories are needed (e.g., mounting a cooling fan directly onto the RF enclosure of the device.



Figure 4 Spectrum of 2 GHz up converted RF signal from 240 MHz; spanned out to 80 MHz



Figure 5 Narrow span RF signal centered at 2.0 GHz

Amplitude Specifications

IF Input range

AC	+17 dBm max
DC ⁽¹²⁾	
Attenuation range	
RF	0 to 60 in 1 dB steps
IF (13)	0 to 60 in 1 dB steps

- (12) Large and fast DC transients could damage the input solid state devices. Slow ramp up of DC to 10 V is sustainable.
- (13) There are two IF attenuators in total, each having 30 dB of attenuation.

Output voltage standing wave ratio (VSWR)

10 MHz to 3.0 GHz	< 2.0
3.0 GHz to 6.0 GHz	< 2.8

Gain (@ 1GHz) (14)

Minimum ⁽¹⁵⁾	90 dB typical
Maximum ⁽¹⁶⁾	30 dB typical

RF amplitude response (15 °C to 35 °C ambient)

RF gain flatness response (uncorrected)	14 dB typical
RF gain flatness response (corrected) ⁽¹⁷⁾	±0.75 dB
Absolute gain accuracy (corrected) (17)	

IF flatness (15 °C to 35 °C ambient)

IF III-DAILU LESDUIISE HAUTESS	IF in-band response flatness	
--------------------------------	------------------------------	--



Figure 6. Typical RF conversion gain response @ 25 °C. IF set to 240 MHz, attenuation set to zero. Filter responses are measured relative to the gain.

IF to RF group delay (80% of IF bandwidth)

3 stage conversion	. 100 ns typical
2 stage conversion	. 100 ns typical

- (14) These are typical gain specifications. The gain of the device is calibrated and stored in the device calibration EEPROM.
- (15) Minimal gain is specified when all attenuators are set to their maximum values.
- (16) Maximum conversion gain is specified when all the attenuators are set to 0 dB attenuation.
- (17) Correction stored in the calibration EEPROM must be applied properly. Users are not obligated to use the calibration provided, they may devise their own method of calibration and correction should they choose to. User methods of calibration and application may improve on the accuracies specified.
- (18) For broadband signal operation, it is recommended that users apply in situ amplitude and phase equalization to the received signal to minimize amplitude and phase errors caused by the device.

Dynamic Range Specifications

Spurious response ⁽¹⁹⁾





Figure 7. Spectrum showing low in-band spurs for RF converted frequencies from 240 MHz IF.

- (19) Spurious responses are unwanted signals appearing at the RF output. All spurious products are referenced to the RF output
- (20) Spurious signals are observed at the RF port that result from higher order mixed products.
- (21) L0 leakages are unwanted signals from the internal oscillators.

Output Signal-to-Noise (15 °C to 30 °C ambient) (22)

	100 MHz	3000 MHz	5500 MHz
Best SNR setting ⁽²³⁾	148 dB/Hz	147 dB/Hz	140 dB/Hz
Best linearity setting ⁽²⁴⁾	126 dB/Hz	124 dB/Hz	120 dB/Hz

(22) passbar	The is the output signal level measured with respect to output noise density within the nd range.
(23)	Requires +5 dBm level at the IF input mixer, and RF output set to $\geq 0 \ dBm$
(24)	Requires -10 dBm level at the IF input mixer, and RF output set to $\leq 0 \ dBm$

Output third-order intermodulation (OIP3, dBm)

	100 MHz - 1.5 GHz	1.5 GHz - 4 GHz	4 GHz – 6 GHz
Best SNR setting ⁽²³⁾⁽²⁵⁾	17	17	15
Best linearity setting (24)(25)	32	31	29





(25) Specifications are based on two 0 dBm tones with 1 MHz separation at the RF output. The IF frequencies were set at 240 ± 0.5 MHz.

Output second harmonic (dBm @ 0 dBm Output)

	500 MHz	1000 MHz	2700 MHz
Harmonic level	-60	-55	-52

Output compression point (dBm)

	100 MHz - 1.5 GHz	1.5 GHz - 4.0 GHz	4.0 GHz - 6.0 GHz
IF3 mixer level = 0 dB	>18	>17	>15



Figure 9. Output RF power vs Gain; RF =2 GHz, IF = 240 MHz, IF level = 0 dBm

Reference Input and Output Specifications

Reference output specifications

Center frequency ⁽²⁶⁾	10 MHz/100 MHz
Amplitude	3 dBm typ
Waveform	Sine
Impedance	
Coupling	AC
Connector type	SMA female
Frequency accuracy	See "Spectral Specifications" section

Reference input specifications

Center frequency	10 MHz
Amplitude	0 dBm min/ +10 dBm max
Phase-lock range	± 3 ppm (typ)
Impedance	50 Ω nominal
Coupling	
Connector type	SMA female

(26) The output reference frequency may be selected programmatically for 10 MHz or 100 MHz.

Port Specifications

RF output

Output impedance	50 Ω
Coupling	
Connector type	SMA female
LO leakage	<-120 dBm

IF input

Input impedance	50 Ω
VSWR	
Coupling	AC
Connector type	SMA female
Output amplitude	20 dBm max

General Specifications

Environmental

Operating temperature ⁽²⁷⁾	-10 °C to +70 °C
Storage temperature	-40 °C to +100 °C
Operating relative humidity	10% to 90%, non-condensing
Storage relative humidity	5% to 90%, non-condensing
Operating shock	30 g, half-sine pulse, 11 ms duration
Storage shock	50 g, half-sine pulse, 11 ms duration
Operating vibration	5 Hz to 500 Hz, 0.31 g_{rms}
Storage vibration	5 Hz to 500 Hz, 2.46 g_{rms}
Altitude 2,000 m maximum (maintaining	g 25 °C maximum ambient temperature)

Physical

Dimensions (W x H x D, max envelope) (SC5408A)	3.7" x 1.4" x 6.1"
Dimensions (W x H x D, max envelope) (SC5407A)	2x3U slots
Weight	2.6 lbs
Input voltage (SC5408A)	
Power consumption	25 W typical
Communication interface	USB and RS-232/ SPI
Safety	Designed to meet the requirements of:

IEC 61010-1, EN 61010-1, UL 61010-1, CSA 61010-1

Electromagnetic Compatibility (EMC) Designed to meet the requirements of: EN 61326-1 (IEC 61326-1): Class A emissions; Basic immunity 1, EN 55011 (CISPR 11) Group 1, Class A emissions, AS/NZS CISPR 11: Group 1, Class A emissions, FCC 47 CFR Part 15B: Class A emissions, ICES-001: Class A emissions

CE Meets the requirements of: 2006/95/EC; Low-Voltage Directive (safety), 2004/108/EC; Electromagnetic Compatibility Directive (EMC Directive)

(27) User-provided cooling solution is required to keep the device less than 15 °C above the ambient temperature. Recommended operating device temperature is 0 °C to 55 °C, as measured by the internal temperature sensor.

Revision Notes

Rev 1.0	Original document	08-15-2016
Rev 1.1	Updated result graphs	04-23-2017
Rev 1.2	Grammar corrections, modified operating temperatures	11-10-2017

© 2017 SignalCore Inc. All rights reserved. Trademarks and registered trademarks are the property of their respective owners.



www.signalcore.com